



GENERAL PURPOSE SILICON RECTIFIER

1N4001~1N4007

General Purpose Silicon Rectifier

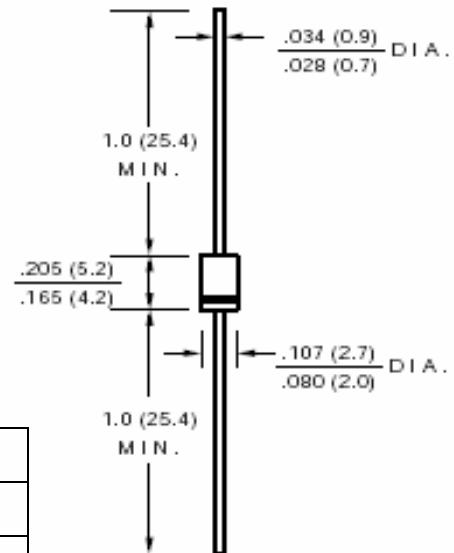
Dimensions in inch (mm)

Features

- Low forward voltage drop
- Low leakage current
- High forward surge current capability
- High temperature soldering guaranteed 260°C/10 seconds
.0375" (9.5mm) lead length
- RoHS and REACH Compliant

Mechanical Data

Case:	DO-41, transfer molded plastic
Epoxy:	Meets UL 94V-0 flammability rating
Terminals:	Plated axial leads, solderable per MIL-STD-202E, Method 208C
Polarity:	Cathode indicated by color band
Mounting position:	Any
Weight:	0.012 Ounce, 0. 33 gram



**DO204AL
(DO-41)**

Maximum Ratings ($T_{Ambient}=25^{\circ}\text{C}$ unless noted otherwise)

Symbol	Description	1N4001	1N4002	1N4003	1N4004	1N4005	1N4006	1N4007	Unit	Conditions
V_{RRM}	Max Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V	
V_{RMS}	Max RMS Voltage	35	70	140	280	420	560	700	V	
V_{DC}	Max DC Blocking Voltage	50	100	200	400	600	800	1000	V	
I_{F(AV)}	Max Average Forward Rectified Current				1.0				A	.0375" (9.5mm) lead length at $TA=75^{\circ}\text{C}$
I_{FSM}	Peak Forward Surge Current				30				A	8.3ms single half sine-wave (JEDEC)
I_{R(AV)}	Max Full Load Reverse Current				30				µ A	Full cycle average .0375" (9.5mm) lead length
T_J, T_{STG}	Operating and Storage Temperature Range				-65 to +175				°C	

MEI

General Purpose Silicon Rectifier

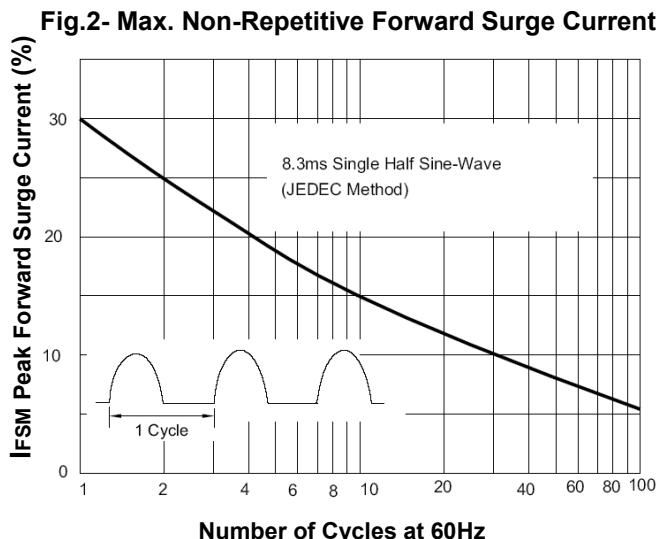
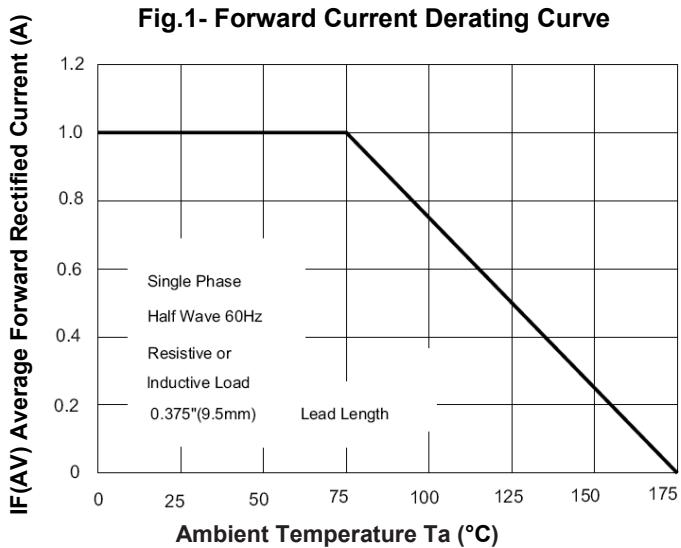
1N4001~1N4007

Electrical Characteristics ($T_{Ambient}=25^{\circ}\text{C}$ unless noted otherwise)

Symbol	Description	1N4001	1N4002	1N4003	1N4004	1N4005	1N4006	1N4007	Unit	Conditions
V_F	Max Instantaneous Forward Voltage	1.1						V		$I_{F(AV)}=1.0\text{A}$
I_R	Max DC Reverse Current at Rated DC Blocking Voltage	5.0						μA		$TA=25^{\circ}\text{C}$
		50								$TA=100^{\circ}\text{C}$
C_J	Typical Junction Capacitance	15						pF	At 1MHz, reversed voltage of 4V	
$R_{\theta-JA}$	Typical Thermal Resistance	50						$^{\circ}\text{C/W}$	Note 2	

- Note:**
1. Single phase, half wave, 60Hz, resistive or inductive load. Derate current by 20% for capacitive load
 2. Thermal resistance from junction to ambient at .375" (9.5mm) lead length, PCB mounted with copper pad area of 0.2" x 0.2" (5x5mm).

Typical Characteristics Curves



MEI

General Purpose Silicon Rectifier

1N4001~1N4007

Fig.3- Typical Instantaneous Forward Characteristics

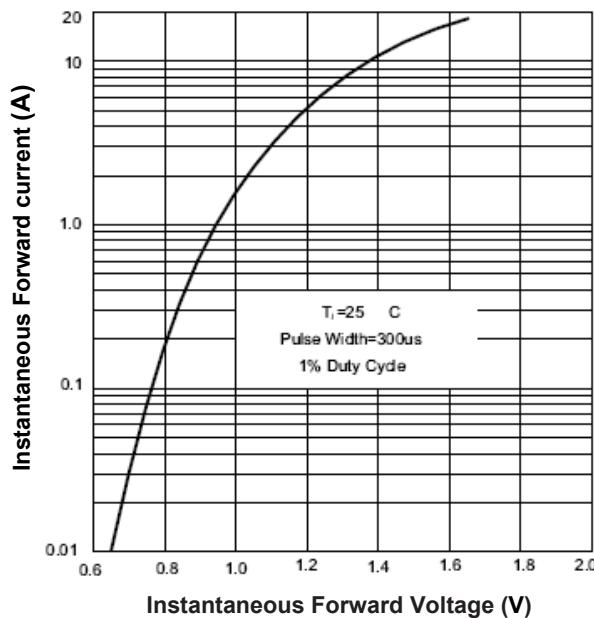


Fig.5- Typical Reverse Characteristics

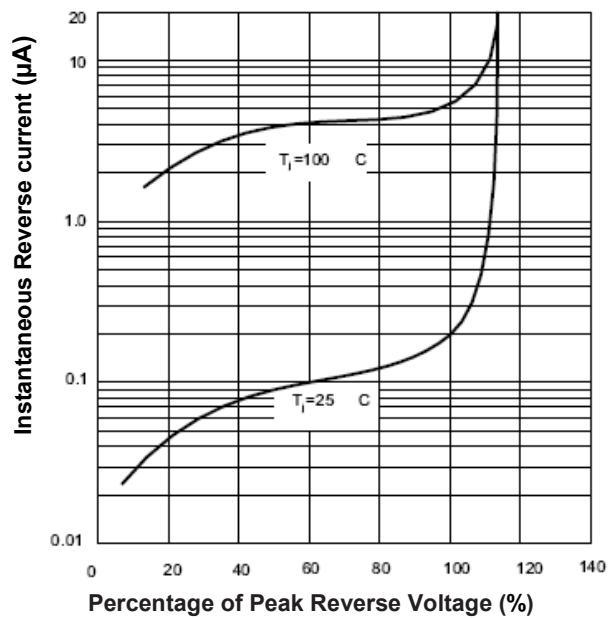


Fig.6- Typical Junction Capacitance

